

# Effect of Additive Concentration during Copper Deposition using EnFACE Electrolyte

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## Abstract

Copper deposition from solutions using high concentration of acid, metal ions and polyethylene glycol (PEG), and bis-(3-sulfopropyl) disulfide (SPS) and chloride ions (Cl<sup>-</sup>) is well known. A recent maskless micropatterning technology, which has the potential to replace traditional photolithographic process, called EnFACE, proposed using an acid-free, low metal ion solution which is in direct contrast to those used in standard plating technology. In this work copper has been deposited using standard electroplating solutions and those used in the EnFACE process. In the standard electrolyte 0.63 M CuSO<sub>4</sub> and 2.04 M H<sub>2</sub>SO<sub>4</sub> has been used, along with Gleam additives supplied by Dow Chemicals. For the Enface electrolyte, copper deposition has been carried out using without any acid, and with different concentrations of additives between 17% - 200% of those recommended by suppliers. 25 μm of metal has been plated on stainless steel coupons as suggested by and ASTM, peeled off and subjected to ductility and resistance measurements. Scanning electron microscopy and electron back scatter diffraction has been carried out to determine the deposit morphology. It was found that copper deposits obtained from acid-free solutions containing low concentration of metal ion and additives produced copper deposits had properties which are comparable to those obtained from standard electrolytes. The optimum additive concentration for the EnFACE electrolyte was 50% of the recommended value.

29 **Keywords:** EnFACE process, copper film, additives, electrodeposition, electroplating.

30

## 31 **1.0 Introduction**

32 Copper is the standard metal used in wiring printed circuit boards [1] and  
33 interconnects in electronic devices [2]. The standard manufacturing process for both these  
34 technologies uses electrodeposition. It is well established that the electrodeposition  
35 processes employ electrolyte chemistry of high metal and acid concentrations and employ  
36 additives, which impart desirable properties to the plated copper [3]. Numerous studies  
37 geared on understanding the role of additives in electroplating have concluded that these  
38 chemicals are essential to obtaining metal deposits of high quality [4-9].

39 Recently a new mask-less process, called EnFACE, has been proposed to deposit  
40 microscale copper features [10]. As opposed to the standard electrolytes used for PCB and  
41 electronic manufacturing, EnFACE proposed a solution using 0.1 M  $\text{CuSO}_4$  and no acid [10-  
42 15]. Since most of the current literature is has been focused on in understanding the role of  
43 additives in the established processes [16-19], the effect on this new chemistry on  
44 deposited copper is still unknown. In addition, it is unclear how much additive is required to  
45 change deposit properties and what effect they would have on the deposit.

46 This work examines the effect of additives on deposit properties when copper is  
47 deposited from EnFACE electrolyte and when additives are added to the bath. The additives  
48 used were Gleam A and B (Dow Chemical) which are used in printed circuit board  
49 manufacturing. The EnFACE electrolyte consisted of a 0.1 M  $\text{CuSO}_4$  solution without addition  
50 of acid. Additive levels of 17%, 33%, 50%, 100% and 200% of that recommended by the  
51 supplier were added to the solution. In addition, a solution of 0.63 M  $\text{CuSO}_4$  with 2.04 M  
52  $\text{H}_2\text{SO}_4$  with additives as per supplier recommendations was also used in plating experiments.

53 Copper films of 25  $\mu\text{m}$  have been plated on polished steel coupons tests in a beaker  
54 without agitation. Deposits were plated from different electrolytes and subjected to  
55 ductility and resistivity tests. Deposit morphology was examined by scanning electron  
56 microscopy and electron back scatter diffraction. Yield strength and sheet resistance were  
57 measured to compare deposit properties against those recommended by Institute of

58 Interconnecting and Packaging Electronic Circuits. Deposit properties are interpreted in  
59 terms of additive concentration in the bath. The effectiveness of using low concentrations of  
60 metal ions and additives on the influence deposit properties has been assessed.

61

## 62 **2.0 Experimental**

### 63 **2.1 Apparatus**

64 Electrodeposition experiments were carried out using a traditional two-electrode  
65 plating set-up. The working electrode was a dog-bone shaped stainless steel coupon with an  
66 area of 31.92 cm<sup>2</sup>. The counter electrode was a copper rod with an exposed area of 58.1  
67 cm<sup>2</sup>. Plating was done in a 2-litre cell using the appropriate plating solution, and the current  
68 source was a Thurlby Thundar PL-310 power unit.

69

70 Morphological analysis (SEM and EBSD) was done using the JEOL JSM-5300LV.  
71 Resistivity of the plated films were measured using the Signatone Pro4 (four point probe)  
72 system in the Electronics and Electrical Engineering department Newcastle University UK.  
73 Mechanical properties were characterized using a Tinius Olsen H50KS with Horizon software  
74 for data recording. All tensile tests followed the ASTM E-345 [20], a standard for  
75 determining tensile properties of metallic films. Morphological and mechanical  
76 characterization were conducted in the Advanced Chemical and Materials Analysis (ACMA)  
77 laboratory, Newcastle University.

78

### 79 **2.2 Chemicals and Electrolytes**

80

81 Steel coupons (308 stainless) were manufactured to the specifications of IPC-TM-650  
82 (IPC-TM stands for The Institute for Interconnecting and Packaging Electronic Circuits  
83 Testing Methods) standard. Technical grade CuSO<sub>4</sub> and H<sub>2</sub>SO<sub>4</sub> (Sigma-Aldrich) were used to  
84 prepare the plating electrolyte. The additives used were commercially available Copper  
85 Gleam series (Rohm Haas). Copper Gleam HS – 200 A served as the accelerator (SPS), while  
86 Copper Gleam B was the inhibitor (PEG). The Cl<sup>-</sup> ions were sourced from concentrated HCl  
87 (37%, Sigma Aldrich). Chemicals for pre-treatment of the coupons include concentrated

88 HNO<sub>3</sub> and ethanol (Sigma Aldrich). The PRP200 photoresist (Electrolube) was used to  
89 insulate the backside of the coupons. Table 1 lists the composition of the different plating  
90 baths used for copper deposition.

91

### 92 **2.3 Procedure**

93 Prior to actual plating, the stainless steel coupons were cleaned with concentrated  
94 HNO<sub>3</sub>, and then rinsed with water for 1 minute. The coupons were mechanically polished  
95 using silicon carbide sheets, starting at grit #220 and progressing to grit #4000. One side of  
96 the coupon was coated with the photoresist, and left to dry. The exposed side of the coupon  
97 was swabbed with ethanol for 30 seconds and again allowed to dry.

98 Electrodeposition was carried out in direct current (DC) mode. The counter and  
99 working electrode was set-up in the plating cell containing different electrolytes. Table 2  
100 shows the plating parameters used for the different experiments. These parameters were  
101 derived from polarization experiments that yielded limiting current regarding each bath  
102 type. Since the deposits become rougher as they approach the limiting current [21], the  
103 current was set at a fraction of this value to ensure that dendritic copper was not plated.  
104 The total plating time was calculated to obtain a copper film with thickness of 25  $\mu\text{m}$ .

105 After the allotted deposition time was reached, the coupons were removed from the  
106 solution and washed with deionized water for 1 minute. The surface was dried using a lint  
107 free cloth and left to dry in air. The plated copper films were then carefully peeled off from  
108 the stainless steel substrate, and were prepared for subsequent characterization. Each  
109 experiment was repeated three times to check for reproducibility.

110 For SEM and EBSD analysis, a 2x2 cm<sup>2</sup> area was cut out from the central portion of  
111 the copper coupon. For mechanical and resistivity testing, the whole coupon was used.  
112 Necessary care was taken to prevent damage on the coupons, particularly during handling  
113 and specimen mounting in the UTM that would compromise the quality of results of the  
114 mechanical tests. The values reported in this manuscript are the average of measurements  
115 from three different films.

116

## 117 3.0 Results and Discussion

### 118 3.1 Morphology and Grain Size Measurements

119 Figure 1 shows the SEM images (planar view) of the products of the EnFACE bath  
120 with different additive concentration and the standard bath. It can be observed that as the  
121 amount of additive increased, the surface roughness of the deposit from the EnFACE bath  
122 noticeably decreased. In fact, the product of the bath with 100% and 200% additive  
123 concentrations appeared the smoothest and most compact among the lot. On the other  
124 hand, in terms of appearance, the deposit from the standard copper bath is similar to that  
125 of the E-33 and E-50 EnFACE bath, which showed that even at low concentrations the  
126 influence of additives is substantial.

127 The observed reduction in surface roughness may indicate the occurrence of a fine-  
128 grained structure in the deposit. However, attempts to quantify the grain size of the copper  
129 films proved difficult since the grain structures were not easily discernible, even when  
130 viewed at high magnifications. Therefore, it became necessary to use another imaging  
131 technique that allowed accurate visualization of grain morphology. Electron back-scatter  
132 diffraction (EBSD) was chosen because the technique allows grain size and grain orientation  
133 analysis without the need to alter the surface condition of the metal.

134 Figure 2 shows the corresponding EBSD maps for the products of the EnFACE bath  
135 with different levels of additive concentration, and of the standard copper bath. The EBSD  
136 images revealed the grain structure, which were predominantly equiaxed for the electrolyte  
137 without additives, and becomes smaller as additive concentration is increased. The EBSD  
138 data allowed measurement of the grain size of deposits.

139 The rightmost column in Table 2 gives a summary of the calculated grain size of  
140 deposits measured using the EBSD image analyzing software TANGO (HKL Technology A/S,  
141 2001). The grain structure map produced in EBSD was processed by performing noise  
142 reduction and wild spikes extrapolation. The band contrast was adjusted to clearly see the  
143 grains. The grain size parameter used is the major and minor axis of the fitted ellipse and  
144 the software automatically measures the grain size based on the delineation of all of the  
145 grain boundaries.

146 Similar to the conclusions made from SEM analysis, the EBSD results indicated that  
147 additives created a finer grain structure in the deposit, and that the decrease in grain size  
148 was proportional to the concentration of additives used. The appearance of small grains  
149 inside the larger ones was further analyzed, and these small grains were identified as sub-  
150 grains brought about by recrystallization. Dynamic recrystallization or self-annealing is a  
151 recognized phenomenon that exclusively occurs in copper plated from additive-containing  
152 electrolytes [22].

153 The SEM and EBSD results validate the grain-refining action of additives on the  
154 copper deposits. While numerous studies have reported similar observations in  
155 conventional copper baths [23, 24, 25], these observations may be the first report on the  
156 effect of additives used for super-filling on the products of the EnFACE bath. It is also  
157 observed that the grain refining effect of additives on the EnFACE bath is more pronounced  
158 than in the standard bath. This was seen with the finer grain size obtained in the EnFACE  
159 copper compared to the standard copper at the same additive concentration.

160 Grain refinement is one of the most important morphological and structural effects  
161 of additives [24]. It is known that additives affect the mechanisms of nucleation and growth  
162 during plating [26]. For example, brighteners enhance nucleation rates, while leveling  
163 agents inhibit dendritic growth. Both these actions can contribute to creating the fine-  
164 grained structure seen in the deposits. The effect could even be synergistic when different  
165 types of additives are present in the electrolyte. Since, grain refinement would affect the  
166 mechanical and electrical properties, these properties were measured and are reported  
167 below.

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### 169 **3.2 Mechanical and Resistance Measurements**

170 Figure 3 shows the resistivity measurements for different additive concentration  
171 using EnFACE electrolyte. Clearly, the progressive addition of additives created a more  
172 resistive copper deposit. Furthermore, the resistivity of some of the EnFACE copper is  
173 similar in value to copper deposited from a standard electrolyte; i.e., the resistivity is 2.27  
174  $\mu\text{ohm-cm}$  when copper is plated from a standard bath, and 2.30 and 2.31  $\mu\text{ohm-cm}$  when  
175 deposited from E-33 and E-50, respectively.

176 The increase in the resistivity of the copper film is explained by the significant  
177 reduction of grain size brought about by additive use. Morphological analysis presented  
178 earlier has already confirmed a change in grain size. Grain boundaries, together with other  
179 defects, act as electron scattering centers and reduce the effective displacement of the free  
180 electrons during electronic conduction [27]. Thus, the increase in grain boundary area  
181 during grain refinement caused the increase resistivity of the deposited film.

182 Figure 4 shows the plot of mechanical properties; namely, 0.2% offset yield strength  
183 (YS), ultimate tensile strength (UTS), and the ductility of the electrodeposited copper films,  
184 as a function of additive concentration. The results reveal the strong effect of additive  
185 concentration on mechanical properties. Both YS and TS increased while ductility decreased  
186 with increasing additive concentrations. The percent increase in YS and TS, and the %  
187 decrease in ductility are almost similar; a ~40% change in value from the lowest to the  
188 highest additive concentration.

189 Table 3 summarises the mechanical properties of copper plated from a standard  
190 bath. The Institute for Interconnecting and Packaging Electronic Circuits advises that copper  
191 for interconnects to have a minimum tensile strength of 207 MPa and ductility of 3% [28].  
192 Using these values, it can be seen that plated films from EnFACE electrolytes are closer to  
193 the specification of the Institution than those obtained from the standard electrolyte. It is  
194 envisaged that by optimising bath and plating conditions, the specifications for  
195 interconnections and packaging can be achieved.

196 The observed trends in the plated copper are consistent with the well-known  
197 mechanical behavior of metals. Typically, an increase in the metal's strength will be  
198 accompanied by a loss in ductility. The results also indicate a clear improvement in the  
199 mechanical strength of the plated copper when additives are used with the bath. To explain  
200 how additive concentration affects mechanical properties, one needs to consider the plated  
201 metal's inherent microstructural features. Important microstructural features include  
202 dislocation, grain boundaries and voids [25].

203 It is reasonable to assume that the observed grain size refinement directly caused  
204 the changes in the metal's yield strength and ductility; a statement consistent with  
205 published work [29, 30, 31]. Classical theories on slip and plastic yielding explain how grain

206 boundaries can serve as dislocation barriers, thereby lowering dislocation mobility and  
207 preventing easy plastic deformation to occur. Consequently, such an action increases YS and  
208 lowers ductility. Tensile strength, on the other hand, is strongly affected by the amount of  
209 voids, and an inverse relation exists between the two.

210

### 211 **3.3 Optimum Additive Concentration**

212 By inspecting the properties of the copper plated from EnFACE electrolytes  
213 containing different concentration of additives, it was found that at an additive  
214 concentration of 50%, the plated copper has properties close to the specifications stated by  
215 IPC. Though the properties of the E-50 electrolyte is slightly different from the values  
216 specified, they are closer than those obtained from a standard electrolyte. It can be  
217 envisaged that further improvements in deposit properties could be obtained by optimising  
218 plating conditions.

219 Notably, the EnFACE electrolyte has a low metal ion concentration, which can limit  
220 plating rates (c.f. Table 2). In fact, the plating rate of the standard electrolyte is nearly four  
221 times higher than the best EnFACE electrolyte (E-50). This means that the rate of plating  
222 needs to be increased by improving agitation. In many industries, such as circuit board  
223 manufacturing, plating rates of 1.5-2.0 ASD (15 - 20 mA/cm<sup>2</sup>) are advised. Since all of the  
224 EnFACE electrolytes exceed this plating rate, it should not affect plating rates in an industrial  
225 environment. On the other hand, by operating baths which have low metal and additive  
226 concentration, savings and sustainability can be achieved.

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### 228 **4.0 Conclusions**

229 Copper was successfully plated from the additive containing EnFACE bath, and its  
230 properties were characterized and compared to that achieved using a standard electrolyte.  
231 Stainless steel coupons were plated with 25 um copper films using electrolytes of different  
232 additive concentrations. Additives caused the refinement of the grain structure of deposits,  
233 and the decrease in grain size was proportional to the concentration of additive used. This  
234 grain refinement consequently increased resistivity, yield and tensile strength, and reduced



235 the ductility of plated copper. The EnFACE bath required a lower amount of additive to  
236 obtain a product that has comparable properties to that obtained from a standard  
237 electrolyte. The optimum additive concentration appears to be about 50% lower than the  
238 industry recommended dosage.

239

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243 \*This work commenced in Newcastle University. Both Newcastle authors have changed  
244 their affiliation to Strathclyde University.

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304 **Figure Captions**

305 Figure 1: SEM images of copper deposits from EnFACE bath with different additive  
306 concentration: a) E-17 with 17% additive concentration, b) E-33 with 33% additive  
307 concentration, c) E-50 with 50% additive concentration, d) E-100 with 100% additive  
308 concentration and e) E-200 with 200% additive concentration, and f) S - standard bath.  
309 These percentages are relative to the industry recommended additive concentration of 10  
310 ml/L Copper Gleam B, 0.5 ml/L Copper Gleam A, and 70 ppm Cl<sup>-</sup>.

311

312 Figure 2: EBSD images of copper deposits from EnFACE bath with different additive  
313 concentration: a) E-17 with 17% additive concentration, b) E-33 with 33% additive  
314 concentration, c) E-50 with 50% additive concentration, d) E-100 with 100% additive  
315 concentration and e) E-200 with 200% additive concentration, and f) S - standard bath.  
316 These percentages are relative to the industry recommended additive concentration of 10  
317 ml/L Copper Gleam B, 0.5 ml/L Copper Gleam A, and 70 ppm Cl<sup>-</sup>. The calibration bar is for 2  
318 um length. The different colors in the EBSD map represent different crystals planes as  
319 described by the g) inverse pole legend.

320

321 Figure 3: Resistivity measurements of electrodeposited copper films using EnFACE  
322 electrolyte with varying additive concentrations.

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324 Figure 4: The a) yield strength, b) tensile strength and ductility of plated copper films using  
325 EnFACE electrolyte with varying additive concentrations.

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335 **Table 1: Bath composition and nomenclature.**

Designation	Setting description	Cu <sub>2</sub> SO <sub>4</sub> M	H <sub>2</sub> SO <sub>4</sub> M	Gleam B ml/L	Gleam A ml/L	HCl ppm
S	Standard bath	0.63	2.04	10	0.5	70
S-0	Standard bath without additives	0.63	2.04	X	X	X
E-0	EnFACE bath without additives	0.1	X	X	X	X
E-17	17% of the recommended additive concentration	0.1	X	1.7	0.08	12
E-33	33% of the recommended additive concentration	0.1	X	3.3	0.17	23
E-50	50% of the recommended additive concentration	0.1	X	5.0	0.25	35
E-100	Recommended additive concentration	0.1	X	10.0	0.50	70
E-200	High concentration (double of the recommended additive)	0.1	X	20.0	1.0	140

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337 "S" stands for "standard" electrolytes based on supplier recommendation and "E" stands for  
 338 "Enface" baths. The number following the "S" and "E" stand for the percent of additive  
 339 concentration added to the electrolyte

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342 **Table 2: Plating parameters**

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Electrolyte	Plating current mA (40% from $I_{LIM}$ )	Plating time minutes	Grain size From EBSD (nm)
S	245	146	431
S-0	255	152	11524
E-0	68	615	9016
E-17	68	623	758
E-33	63	623	523
E-50	58	669	466
E-100	54	705	407
E-200	53	708	400

358 **Table 3: Mechanical properties of copper plated from S, S-0 and E-50 bath.**

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Bath	YS <sub>0.2%</sub> , MPa	TS, MPa	Ductility, %
S	219	256	1.69
S-0	136	145	2.77
E-50	170	213	2.17

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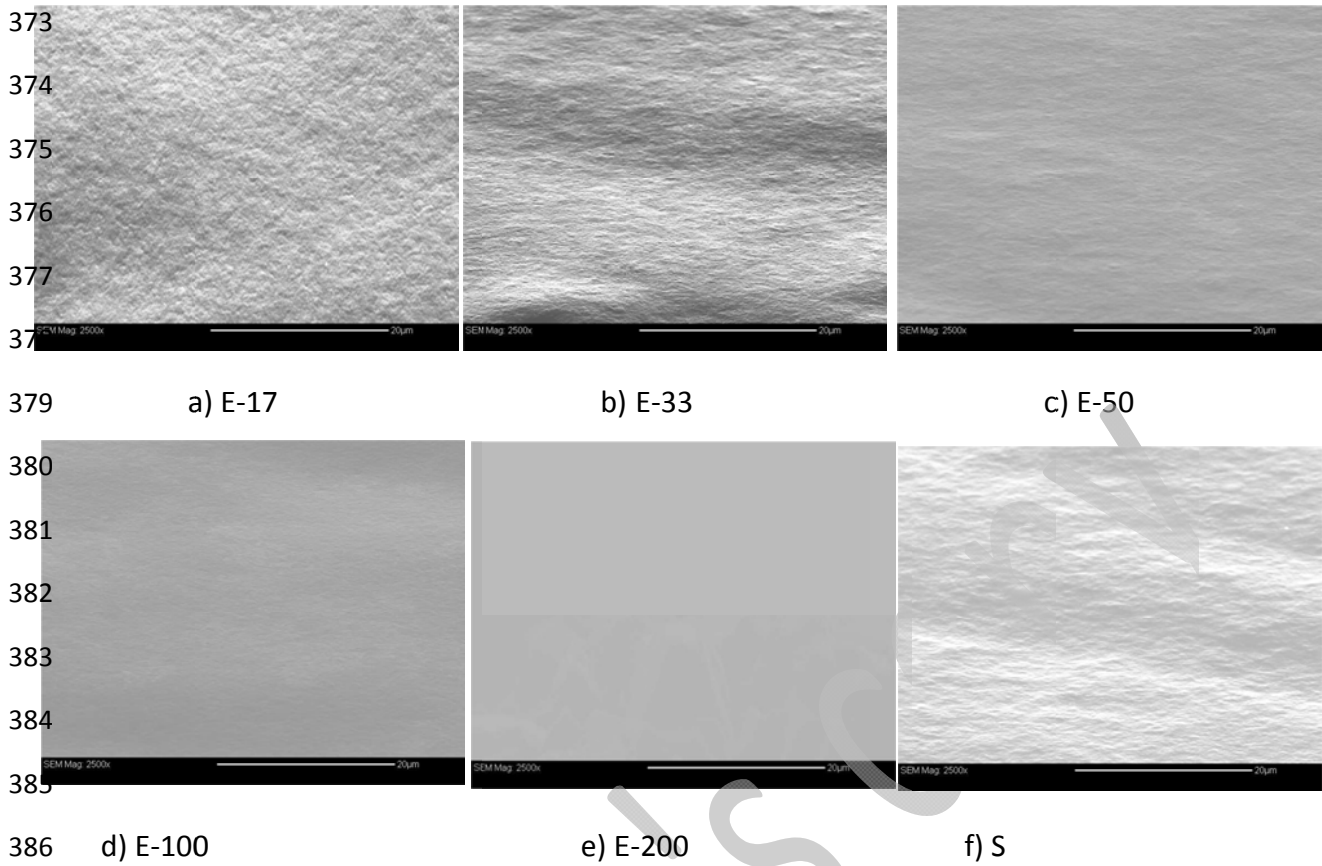
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**Figure 1:** SEM images of copper deposits from EnFACE bath with different additive concentration: a) E-17 with 17% additive concentration, b) E-33 with 33% additive concentration, c) E-50 with 50% additive concentration, d) E-100 with 100% additive concentration and e) E-200 with 200% additive concentration, and f) S - standard bath. These percentages are relative to the industry recommended additive concentration of 10 ml/L Copper Gleam B, 0.5 ml/L Copper Gleam A, and 70 ppm Cl<sup>-</sup>.



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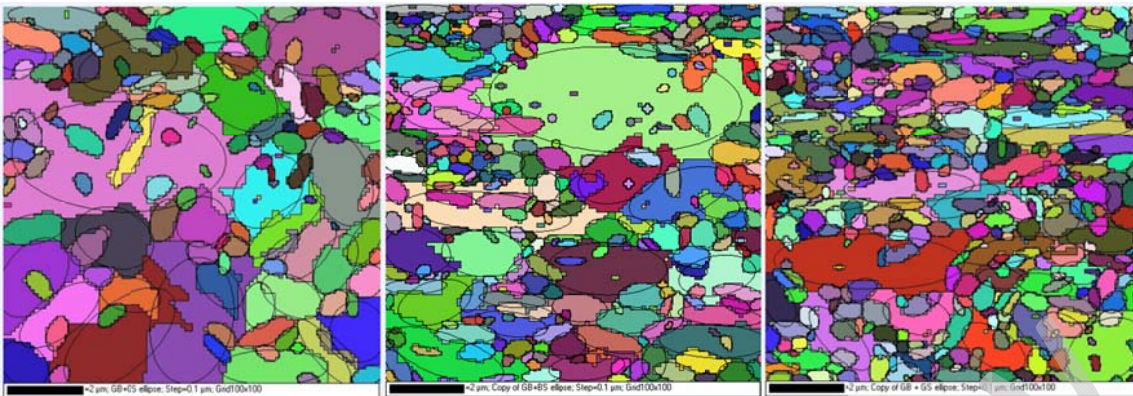
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a) E-17

b) E-33

c) E-50

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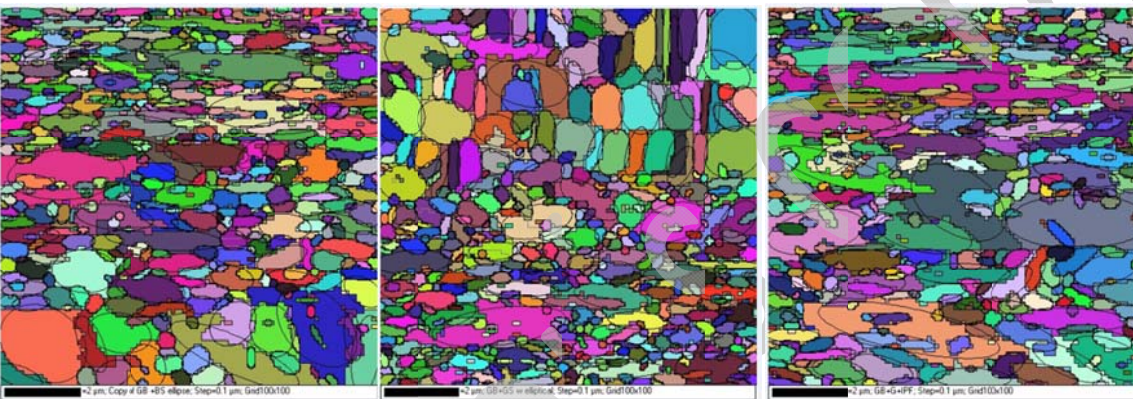
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d) E-100

e) E-200

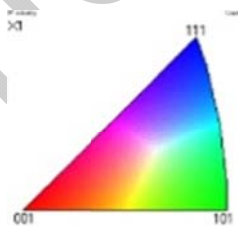
f) S

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g) Inverse pole legend

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**Figure 2:** EBSD images of copper deposits from EnFACE bath with different additive concentration: a) E-17 with 17% additive concentration, b) E-33 with 33% additive concentration, c) E-50 with 50% additive concentration, d) E-100 with 100% additive concentration and e) E-200 with 200% additive concentration, and f) S - standard bath. These percentages are relative to the industry recommended additive concentration of 10 ml/L Copper Gleam B, 0.5 ml/L Copper Gleam A, and 70 ppm Cl<sup>-</sup>. The calibration bar represents a length of 2 μm. The different colors in the EBSD map represent different crystals planes as described by the g) inverse pole legend.

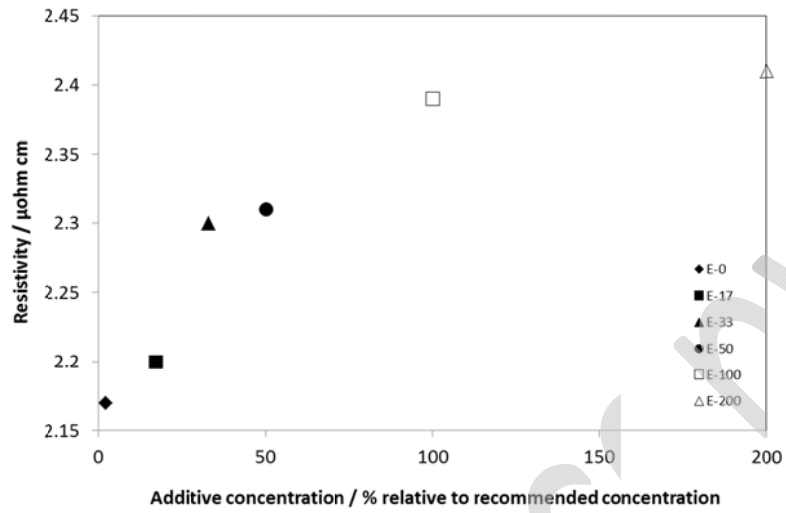
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437 **Figure 3: Resistivity measurements of electrodeposited copper films using EnFACE**  
438 **electrolyte with varying additive concentrations.**

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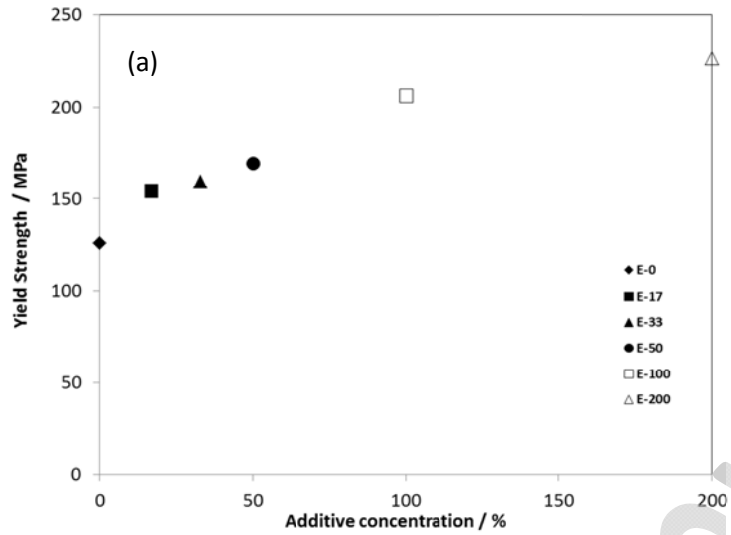
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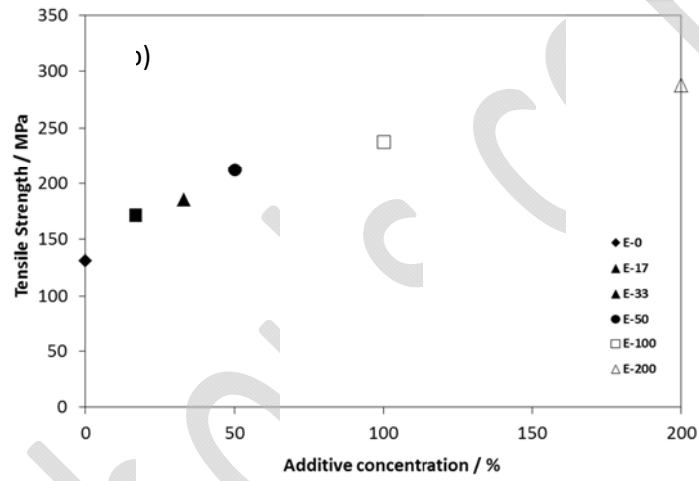
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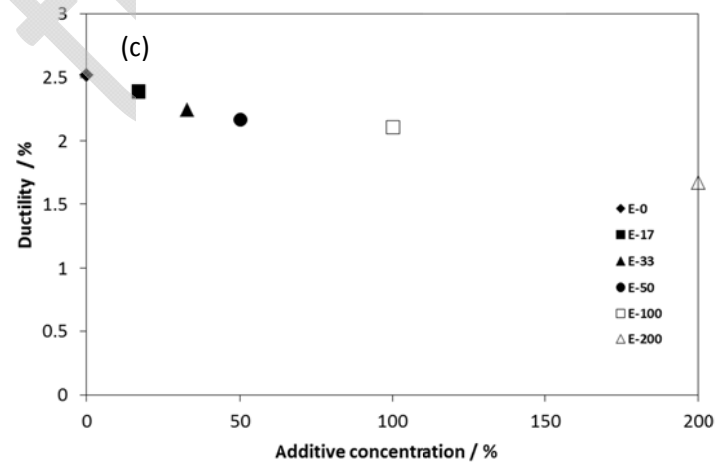
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457 **Figure 4: The a) yield strength, b) tensile strength and ductility of plated copper films**  
458 **using EnFACE electrolyte with varying additive concentrations.**